

L Number	Hits	Search Text	DB	Time stamp
1	7596	Gallium adj nitride	USPAT; US-PGPUB; EPO; JPO; DERWENT; IBM_TDB	2004/10/15 10:51
2	1775582	substrate	USPAT; US-PGPUB; EPO; JPO; DERWENT; IBM_TDB	2004/10/15 10:51
3	578	(Gallium adj nitride) near substrate	USPAT; US-PGPUB; EPO; JPO; DERWENT; IBM_TDB	2004/10/15 10:52
4	1067	low adj dislocation	USPAT; US-PGPUB; EPO; JPO; DERWENT; IBM_TDB	2004/10/15 10:52
5	274009	extra	USPAT; US-PGPUB; EPO; JPO; DERWENT; IBM_TDB	2004/10/15 10:53
6	5	(low adj dislocation) near extra	USPAT; US-PGPUB; EPO; JPO; DERWENT; IBM_TDB	2004/10/15 10:53
7	4	((Gallium adj nitride) near substrate) and ((low adj dislocation) near extra)	USPAT; US-PGPUB; EPO; JPO; DERWENT; IBM_TDB	2004/10/15 10:55
8	55	(low adj dislocation) and ((Gallium adj nitride) near substrate)	USPAT; US-PGPUB; EPO; JPO; DERWENT; IBM_TDB	2004/10/15 11:10
9	287303	257/\$.ccls.	USPAT; US-PGPUB; EPO; JPO; DERWENT; IBM_TDB	2004/10/15 11:11
10	45	((low adj dislocation) and ((Gallium adj nitride) near substrate)) and 257/\$.ccls.	USPAT; US-PGPUB; EPO; JPO; DERWENT; IBM_TDB	2004/10/15 11:11